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INFORMATION DISCLOSURE

STATEMENT BY APPLICANT

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First Named Inventor

Nak-Kyt Park

Art Unit

Examiner Name

David LAW

Attorney Docket Number

51876P541

U.S. PATENT DOCUMENTS							
Examiner Initiats*	Cite No.¹	Document Number  Number - Kind Code <sup>2</sup> (if known)	Publication Date or Issue Date MM-OD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
DL		US-2003/0154417 A1	08-14-2003	Drexler	/		
1		US-2003/0117881 A1	06-26-2003	Johnson et al.			
		US-6,584,578 B1	06-24-2003	Faue			
		US-2003/0095444 A1	05-22-2003	Ryu et al.	7		
		US-2003/0081713 A1	05-01-2003	Pontius et al.			
		US-6,538,956 B2	03-25-2003	Ryu et al.			
		US-6,476,652 B1	11-05-2002	Lee et al.			
		US-2002/0001240 A1	01-03-2002	Ryu et al.			
		US-2003/0002357 A1	01-02-2003	Kwon et al.			
DL		US-6,333,896 B1	12-25-2001	Lee	7		
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FOREIGN PATENT DOCUMENTS									
Examiner Initials*	Cite No.¹	Foreign Patent Document			Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T°			
		Country Code <sup>3</sup> - Number <sup>4</sup> - Kind Code <sup>5</sup> (If known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document					
DL		JP 2003-132680	05-09-2003	Hynix Semiconductor Inc.		abla			
		JP 2003-045183	02-14-2003	Hynix Semiconductor Inc.	. /				
		JP 2002-056677	02-22-2002	HYynix Semiconductor Inc.					
		JP 2001-068650	03-16-2001	Hitachi Ltd.		Г			
DL		JP 11-353878	12-24-1999	Fujitsu Ltd.					
						-			

Examiner	417	Date	11/100	
Signature	Do for	Considered	4/05	

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Based on PTO/SB/08A (08-03) as modified by Blakely, Solokoff, Taytor & Zalman (wir) 08/11/2003.